TOSHIBA Photocoupler IRED & Photo-IC

TLP716F

Plasma display panel High Speed Interface Factory Automation

TOSHIBA

The TOSHIBA TLP716F consists of an infrared emitting diode and a high speed photodetector. This unit is 6-lead SDIP. TLP716F is 50% smaller than 8PIN DIP and has suited the safety standard reinforced insulation class. So, mounting area in safety standard required equipment can be reduced.

- Inverter Logic (totempole output)
- Package Type : SDIP6
- Guaranteed Performance Over Temperature : -40 to 100°C
- Power Supply Voltage: 4.5 to 5.5 V
- Input Thresholds Current: IFHL = 6.5 mA (max)
- Propagation delay Time (tpHL/tpLH): 75 ns (max)
- Switching speed: 15 MBd (typ.)
- Common mode transient immunity: ±10 kV/µs (min)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349

Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

Construction Mechanical Rating

-M1

OFF

ON

M2

ON

OFF

Creepage Distance

Insulation Thickness

Clearance

LED

ON

OFF

Truth Table

Input

Н

L

CUL-recognized: CSA Component Acceptance Service No.5A
 File No.E67349

8.0 mm (min)

8.0 mm (min)

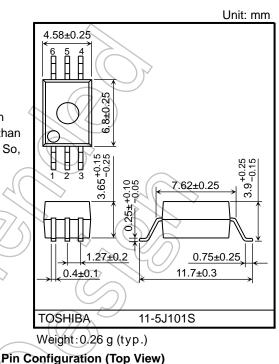
0.4 mm (min)

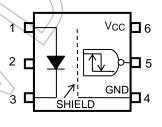
Output

Н

 $\langle \hat{1} \rangle$

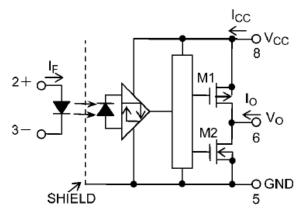
VDE-approved : EN 60747-5-5 , EN 62368-1 (Note 1)





- 1: ANODE
- 2: N.C.
- 3: CATHODE
- 4: GND
- 5: VO
- 6: VCC

Schematic



Note: 0.1 μ F bypass capacitor must be connected between pins 6 and 4.

Start of commercial production 2006-06

2019-06-03

Absolute Maximum Ratings (Ta=25°C)

					1	
	CHARACTERISTIC	SYMBOL	RATING	UNIT		
	Forward Current (Ta ≤ 85°C)	lF	20	mA		
	Forward Current Derating (Ta > 85°C)	∆I _F /∆Ta	-0.5	mA/°C		
0	Peak Transient Forward Current (Note1)	IFPT	1	А		
LED	Reverse Voltage	VR	5	X		
	Diode power dissipation	PD	40	mW		
	Diode power dissipation derating (Ta >85°C)	∆P _D /∆Ta	-1.0	mW/°C		
	Junction Temperature	Tj	125	⊃°C		
	Output Current (Ta ≤ 85°C)	IO	10) mA		
	Output Current Derating (Ta > 85°C)	∆lo/∆Ta	-0.25	mA/°C		
DETECTOR	Output Voltage ($V_O \leq V_{CC}$)	Vo	-0.5 to 6	V		
	Supply Voltage	Vcc	-0.5 to 6	V	(
	Power Dissipation (Ta $\leq 85^{\circ}$ C)	Pc <	40	mW	$\left(\right)$	
	Power Dissipation Derating (Ta > 85°C)	ΔP _C /ΔTa	-1.0	mW/°C		
	Junction Temperature	тј (//	125	(°C)		
Oper	ating Temperature Range	Topr	-40 to 100	°C	\bigcirc	
Stora	ge Temperature Range	T _{stg}	-55 to 125	⊃° ⊂	9	
Lead	Solder Temperature(10 s)	T _{sol}	260	°C		
Isolat	ion Voltage (AC, 60 s, R.H. ≤ 60 %) (Note2)	BVs	5000	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

- Note 1: Pulse width PW \leq 1 µs, 300 pps.
- Note 2: Device Considered a two terminal device: pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Input Current, ON	IF(ON)	8	12	18	mA
Input Voltage, OFF	VF(OFF)	0		0.8	V
Supply Voltage (Note1)(Note2)(Note 3)	Vcc	4.5	5	5.5	V

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: This item denotes operating ranges, not meaning of recommended operating conditions.

- Note 2: The detector of this product requires a power supply voltage (V_{CC}) of 4.5 V or higher for stable operation. If the V_{CC} is lower than this value, an I_{CC} may increase, or an output may be unstable. Be sure to use the product after checking the supply current, and the operation of a power-on/-off.
- Note 3: A ceramic capacitor (0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

The correlation between input current and switching speed and drive circuit (reference information)

Input Current (IF)	TEST CIRCUIT (Psge 4)	Typical Switching Speed
12mA	1	14 – 16 MBd
8mA	1	11 – 13 MBd
8mA	2 (with Speed up capacitor)	16 – 20 MBd

Electrical Characteristics

(Unless otherwise specified, Ta = -40 to 100° C, V_{CC} = 4.5 to 5.5 V)

CHARACTERISTIC	SYMBOL		MIN	TYP.	MAX	UNIT
Input Forward Voltage VF I		I _F = 10 mA, Ta = 25 °C	7	1.65	1.8	V
Temperature Coefficient of Forward Voltage	ΔV _F /ΔTa	IF = 10 mA	↓	-2.0	\mathcal{O}	mV/°C
Input Reverse Current	I _R	V _R = 5 V, Ta = 25 °C	-((10	μA
Input Capacitance	Ст	V = 0 V, f = 1 MHz, Ta = 25 °C	_0	45	_	pF
Logic Low Output Voltage	Vol	IoL = 1.6 mA, IF = 12 mA VCC = 5 V	A		0.4	V
Logic High Output Voltage	Vон	IOH = -0.02 mA, VF = 1.05 V V _{CC} = 5 V	4.0		_	V
Logic Low Supply Current	ICCL	IF = 12 mA	//_	—	5.0	mA
Logic High Supply Current	ЛССН	VF = 0 V			5.0	mA
Input Current Logic Low Output		lo = 1.6 mA, Vo < 0.4 V	_		6.5	mA
Input Voltage Logic High Output	VFLH	Io = -0.02 mA, Vo > 4.0 V	0.8	_	_	V

Note: All typical values are at Ta = 25 °C, Vcc = 5 V, IF(ON) = 12 mA unless otherwise specified

Isolation Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Capacitance input to output	Cs	VS = 0 V , f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	R.H. ≤ 60 %, V _S = 500 V	1×10 ¹²	10 ¹⁴		Ω
Isolation voltage	BVs	AC, 60 s	5000	_	-	Vrms

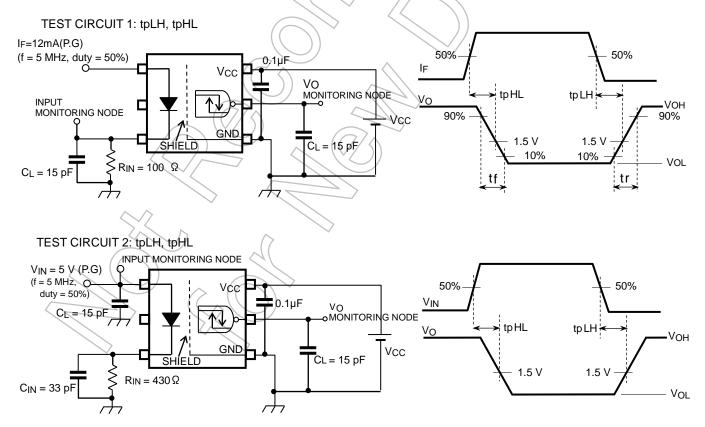
Note : Device Considered a two terminal device: pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

Switching Characteristics (Unless otherwise specified, Ta = -40 to 100°C, V_{CC} = 4.5 to 5.5 V)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	CONDITION		MIN	TYP.	MAX	UNIT
propagation Delay Time to Logic Low output	tpHL		I _F = 0→12mA	RIN = 10 0Ω	_	_	75	ns
propagation Delay Time to Logic High output	tpLH	1	I _F =12→0 mA	CL = 15 pF (Note 1)	X	_	75	ns
propagation Delay Time to Logic Low output	tpHL	2	V _{IN} = 0→5 V (IF = 0→8 mA)	$R_{IN} = 430 \Omega$ $C_{IN} = 33 pF$ $C_{L} = 15 pF$ $(Note 1)$	\mathcal{D}_{λ}	>	65	ns
propagation Delay Time to Logic High output	tpLH		V _{IN} = 5→0 V (I _F = 8→0 mA))_	—	65	ns
Switching Time Dispersion between ON and OFF	tpLH - tpHL		I _F = 12 mA, R _{IN} C _L = 15 pF	= 100 Ω, (Note 1)	_	(45	ns
Output Fall Time (90 to 10%)	tf	1	I _F = 0→12 mA	$R_{\rm IN} = 100 \Omega$	-<	15	\rightarrow	ns
Output Rise Time (10 to 90%)	tr		IF = 12→0 mA	CL = 15 pF (Note 1)	6	15	_	ns
Common Mode transient Immunity at High Level Output	СМ _Н		Vcm = 1000 Vp- Vo(Min) = 4 V, Ta		10000	Ð		V/µs
Common Mode transient Immunity at Low Level Output	CML	3	V _{CM} = 1000 Vp-p, I _F = 12 mA, V _{O(Max)} = 0.4 V, Ta = 25 °C		-10000	—	_	V/µs

Note: All typical values are at Ta = 25 °C

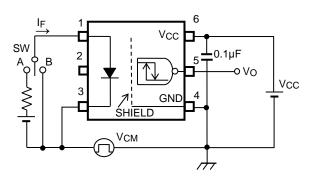
Note 1: CL is approximately 15 pF which includes probe and Jig/stray wiring capacitance.

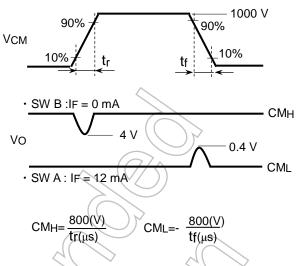


The PROBE and JIG capacitances are included in CL. (P.G): Pulse Generatior

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TEST CIRCUIT 3: Common-Mode Transient Immunity Test Circuit





Note: CML (CMH) is the maximum rate of fall (rise) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

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